

# SR735 THRU SR760 (SINGLE CHIP)

## 7.5AMPS. SCHOTTKY BARRIER RECTIFIERS

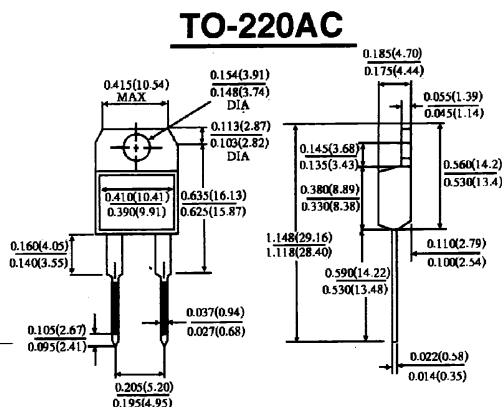


### FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V - 0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds.
- 0.25" (6.35mm) from case

### MECHANICAL DATA

- Case: JEDEC TO - 220AC molded plastic body
- Terminals: Lead solderable per MIL - STD - 750, method 2026
- Polarity: As marked
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified, Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.)

		Symbols	SR735	SR745	SR750	SR760	Units
Maximum repetitive peak reverse voltage		$V_{RRM}$	35	45	50	60	Volts
Maximum RMS voltage		$V_{RMS}$	25	32	35	42	Volts
Maximum DC blocking voltage		$V_{DC}$	35	45	50	60	Volts
Maximum average forward rectified current (see Fig.1)		$I_{(AV)}$	7.5				Amps
Repetitive peak forward current(square wavr, 20KHZ) at $T_c = 105^{\circ}C$		$I_{FRM}$	15.0				Amps
Peak forward surge current 8.3ms single half sine – wave superimposed on rated load (JEDEC method)		$I_{FSM}$	150.0				Amps
Maximum instantaneous forward voltage at 7.5 A( Note 1)		$V_F$	0.65		0.75		Volts
Maximum instantaneous reverse current at rated DC blocking voltage( Note 1)	$T_A = 25^{\circ}C$	$I_R$	1.0				mA
	$T_A = 125^{\circ}C$		15		50		
Typical thermal resistance ( Note 2)		$R_{\theta JC}$	2.5				$^{\circ}C/w$
Operating junction temperature range		$T_J$	– 65 to + 150				$^{\circ}C$
Storage temperature range		$T_{STG}$	– 65 to + 150				$^{\circ}C$

Notes: 1. Pulse test: 300μs pulse width, 1% duty cycle

2. Thermal resistance from junction to case



# RATINGS AND CHARACTERISTIC CURVES SR735 THRU SR760(SINGLE CHIP)

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FIG.1 - FORWARD CURRENT DERATING CURVE

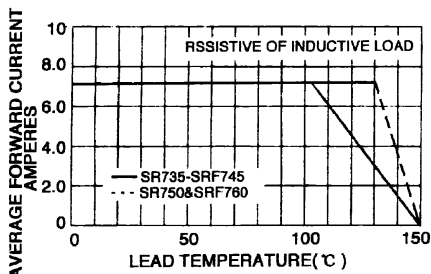


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

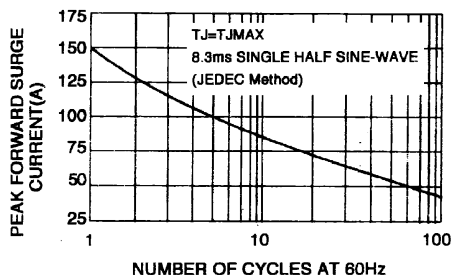


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

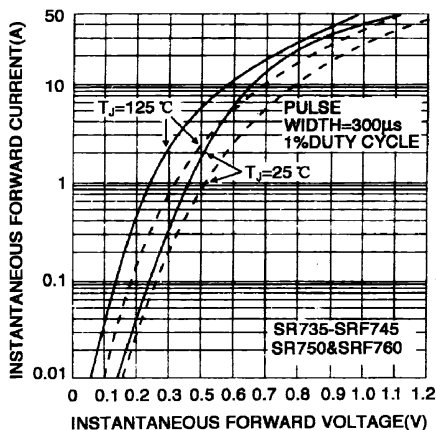


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

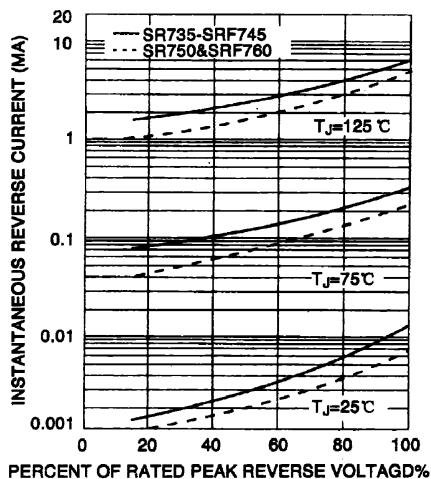


FIG.5 - TYPICAL JUNCTION CAPACITANCE

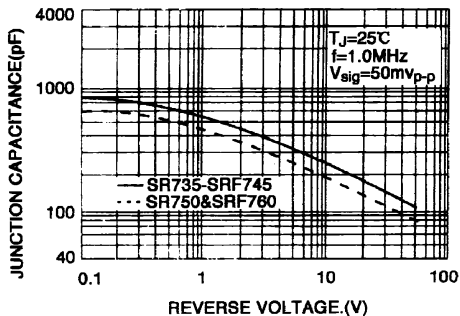


FIG.6 - TYPICAL TRANSIENT THERMAL IMPEDANCE

